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Acetylene hydrogenation catalyzed by bare and Ni doped CeO₂(110): The role of frustrated Lewis pairs

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Abstract

Ceria (CeO_2) has recently been found to catalyze the selective hydrogenation of alkynes, which has stimulated much discussion on the catalytic mechanism on various facets of the reducible oxide. In this work, the H₂ dissociation and acetylene hydrogenation on bare and Ni doped $CeO_2(110)$ surfaces are investigated using density functional theory (DFT). Similar to that on the $CeO_2(111)$ surface, our results suggest that the catalysis is facilitated by frustrated Lewis pairs (FLPs) formed by oxygen vacancies (O_v s) on the oxide surfaces. On bare CeO₂(110) with a single O_v (CeO₂(110)-O_v), two surface Ce cations with one non-adjacent O anion are shown to form (Ce³⁺-Ce⁴⁺)/O quasi-FLPs, while for the Ni doped CeO₂(110) surface with one (Ni- $CeO_2(110)-O_v$) or two (Ni-CeO₂(110)-2O_v) O_vs, one Ce and a non-adjacent O counterions are found to form a mono-Ce/O FLP. DFT calculations indicate that Ce/O FLPs facilitate the H₂ dissociation via a heterolytic mechanism, while the resulting surface O-H and Ce-H species catalyze the subsequent acetylene hydrogenation. With $CeO_2(110)-O_v$ and Ni-CeO₂(110)-2O_v, our DFT calculations suggest the first hydrogenation step is the rate-determining step with a barrier of 0.43 and 0.40 eV, respectively. For Ni-CeO₂(110)-O_v, the reaction is shown to be controlled by the H₂ dissociation with a barrier of 0.41 eV. These barriers are significantly lower than that (about 0.7 eV) on CeO₂(111), explaining the experimentally observed higher catalytic efficiency of the (110) facet of ceria. The change of rate-determining step is attributed to the different electronic properties of Ce in the Ce/O FLPs – the Ce f states closer to Fermi level facilitate the heterolytic dissociation of H₂ but also leads to the higher barrier of acetylene hydrogenation.

Key words: acetylene hydrogenation; oxygen vacancy; Ni doped CeO₂(110); frustrated Lewis pairs

1. Introduction

The selective hydrogenation of alkynes to alkenes is an important step in alkenes polymerization, as acetylenic impurities from steam cracking of crude oil can poison the polymerization catalysts.¹ Although Pd catalysts are commonly used for this purpose,²⁻⁴ they suffer from low selectivity due to over-hydrogenation and oligomerization.^{1,4,5} Furthermore, the scarcity of the precious metal has become exacerbated recently because of high demand and limited supply. As a result, searching for alternative cost-effective catalysts for selective alkyne hydrogeneration has attracted considerable recent interest.

Recently, ceria (CeO_2) has emerged as a surprising catalyst for selective hydrogenation reactions.⁶⁻¹⁷ This oxide is an attractive substitution of the Pd catalysts because it is abundant and relatively inexpensive. In 2012, Vilé et al. reported for the first time that CeO₂ is a highly selective catalyst for the partial hydrogenation of propyne and ethyne.¹² However, its practical application was somewhat limited by the high reaction temperature (above 500 K) required for its activity. This discovery has since stimulated several mechanistic investigations aimed at a better understanding of the hydrogenation mechanism on CeO₂,¹⁸⁻²³ which could help the design of more effective catalysts. In 2014, Carrasco et al. proposed a mechanism based on density functional theory (DFT), which suggested that C_2H_2 on $CeO_2(111)$ is hydrogenated by surface O-H groups generated by the homolytic H₂ dissociation.¹⁸ However, the calculated barrier of the second hydrogenation step ($C_2H_3^* + H^* \rightarrow C_2H_4$) is as high as 2.86 eV, rendering this mechanism unrealistic. Also based on DFT, some of current authors proposed more recently a different mechanism based on surface oxygen vacancies ($O_v s$) on CeO₂(111), which promote heterolytic H₂ dissociation.²³ Specifically, the resulting Ce and O near the O_v help to form frustrated Lewis pairs (FLPs), which are spatially non-contacting acid-base pairs,^{24, 25} on the catalytic surface.^{11, 19, 23}

Such surface FLPs have been shown to activation of small molecules, such as CO₂ and H₂.²⁶⁻³¹ The Ce cations exposed by O_vs play a vital role in the lowering of reaction barrier, by not only stabilizing the Ce-H hydride but also avoiding the strong adsorption of intermediate C₂H₃. The calculated rate-determining barrier in the new mechanism is 0.70 eV, which is significantly lower than that (2.86 eV) of the mechanism proposed by Carrasco et al.¹⁸ This new mechanism was further supported by the observation of Ce-H hydrides in neutron scattering experiment,³² which are absent in the mechanism of Carrasco et al.,¹⁸ and was also corroborated by electron spin resonance and electron energy loss spectroscopy spectroscopic signatures.^{33, 34} More recently, the involvement of surface hydrides in acetylene hydrogenation on reduced ceria was further confirmed by the *in situ* inelastic neutron scattering spectroscopy,⁶ providing definitive evidence for our hydrogenation mechanism based on H₂ heterolytic dissociation.

Moreover, metal doping seems to enhance the activity of the ceria catalyst in selective hydrogenation. For example, Ga was introduced into CeO₂ by the Pérez-Ramírez group to lower the reaction temperature of the catalyzed acetylene hydrogenation.²⁰ Theoretically, this was attributed to Ga/O FLPs induced by O_vs on Ga doped CeO₂(111), which facilitate in the heterolytic dissociation of H₂ and the subsequent hydrogenation step.²² To increase the catalytic efficiency of CeO₂, a new catalyst design based Ni doping was proposed to promote the formation of O_vs on CeO₂(111) surfaces, which was confirmed by experiment.²³ In this case, the Ni dopant was not directly involved in the FLP-facilitated catalysis, but served as a single atom promoter for the formation of oxygen vacancies. The vital role of O_vs in hydrogenation reactions was also found on several other oxides, including the tungsten oxide, indium oxide, bimetal oxide, and titanium dioxide.³⁵⁻³⁹

It is well established that the catalytic activity of ceria is facet dependent.^{11, 13, 14, 40-46} For example, the heterolytic dissociation of H_2 on stoichiometric $CeO_2(110)$ is easier than on the $CeO_2(111)$ counterpart and the stability of the hydride species is related to the coordination number of Ce on various CeO₂ surface such as CeO₂(221), CeO₂(223), and CeO₂(132), etc.^{19, 45-47} Vilé et al.¹³ reported that $CeO_2(111)$ was more active than $CeO_2(100)$ for acetylene hydrogenation. Chang and coauthors found that $CeO_2(110)$ and $CeO_2(100)$ with O_vs are efficient catalysts for hydrogenation of alkenes and alkynes.^{11, 19} More recently, Cao et al. reported that CeO₂ rod dominated by the (110) facet show the highest catalytic performance for acetylene hydrogenation among all ceria facets.¹⁴ On CeO₂(110), again, the regulated O_vs were believed to lead to the formation of the Ce/O FLPs, which promote the H₂ heterolytic dissociation with a small barrier and leads to a much lower rate-determining barrier (0.58 eV) for acetylene hydrogenation.¹⁹ In this work, we extend our theoretical investigation on ceria based hydrogenation catalysis to a different facet of the CeO_2 surface ($CeO_2(110)$). We further study the impact of metal doping, which is expected to promote the formation of O_vs on CeO₂(110).⁴⁸⁻⁵³ To facilitate the comparison with the results based on CeO₂(111),²³ the adsorption and reaction properties of H_2 and C_2H_2 on bare and Ni doped $CeO_2(110)$ model surfaces with O_vs are calculated by using DFT. The results suggest that the catalytic mechanism on the (110) facet of ceria is similar to that on the (111) facet, but with a lower overall barrier, consistent with previous theory¹⁹ and in good agreement with experimental observations.¹⁴ Furthermore, our calculations suggest that Ni doping on CeO₂(110) helps the formation of the O_vs on the surface which induces a mono-Ce/O FLP to facilitate the H₂ dissociation and C₂H₂ hydrogenation. This publication is organized as follows: Section II provides the computational details. The calculated results and discussions are presented in Section III. The conclusions are discussed in the final section.

2. Computational details

All calculations were performed with spin-polarized DFT as implemented in Vienna Ab initio Simulation Package (VASP).^{54, 55} The exchange-correlation potential was treated by the Perdew-Burke-Ernzerhof (PBE) gradient-corrected approximation.⁵⁶ The van der Waals correction was included using the DFT-D3 method of Grimme.⁵⁷ The wave functions for the valence electrons were expanded in plane waves up to a cutoff energy of 400 eV, while the core electrons were described by projector augmented-wave (PAW) method.⁵⁸ In order to properly describe the behavior of Ce *f* electrons, the DFT+*U* method with an effective *U* of 4.5 eV was used.⁵⁹⁻⁶¹ The CeO₂(110) surface was modeled by a $p(2 \times 3)$ five-atomic-layer supercell with the bottom two layers fixed while the other layers fully relaxed. For Ni doped CeO₂, a surface Ce was substituted by a Ni. A vacuum space of 14 Å was employed between the neighboring interleaved slabs. A $1\times1\times1$ and a $5\times5\times1$ Monkhorst-Pack mesh *k*-points for relaxation and calculations of electronic properties, respectively. The dipole correction was employed in all calculations. The parameters were tested for convergence.

Transition states (TSs) were determined using the climbing image nudged elastic band (CI-NEB) method,⁶² with no spin constrained. All structures were relaxed with the convergence criteria of 0.05 eV/Å and 10⁻⁴ eV for forces on each ion and for energy, respectively, while for electronic properties, the criterium was increased to 10⁻⁶ eV for energy. The adsorption energy of a pertinent species was computed as follows: $E_{ads} = E_{(adsorbate + surface)} - E_{(free molecule)} - E_{(free surface)}$. The reaction energy (ΔE) is given by the energy difference between an initial state (IS) and a final state (FS), and the activation energy (E_a) was calculated by the energy difference between IS and TS. The

formation energy of an O_v was obtained by the following equation: $E_f = E(\text{surface-}O_v) + 1/2E(O_2) - E(\text{surface})$, while the formation energy of a second O_v was calculated using the equation $E_f = E(\text{surface-}2O_v) + 1/2E(O_2) - E(\text{surface-}O_v)$. The binding energy of a Ni atom on CeO₂(110) was computed by the equation $E_b = E(\text{slab}) + E(\text{Ni}) - E(\text{Ni-slab})$. Here E(Ni-slab), E(slab) and E(Ni) indicate the energy for Ni doped CeO₂(110), CeO₂(110) with one Ce vacancy and a Ni atom, respectively.

The metal cations on the surface of the oxide can be considered as a Lewis acid because of their ability to accept electrons, while the oxygen anions on the same surface behave as a Lewis base. If the acid and base are adjacent to each other within a bonding distance (1-2 Å), they are often considered as a classical Lewis pair (CLP). However, if the combination of the Lewis pair is sterically encumbered with the distance between them being more than about 2 Å, ¹⁹ they are qualified as an FLP.^{24, 25, 28, 63} CLPs are typically less active than FLP in catalysis since FLPs are essential in creating a local environment that is conducive to catalysis.⁶⁴

3. Results and discussion

3.1 Models for bare and Ni doped CeO₂(110) surfaces

The optimized geometries of the CeO₂(110) and Ni doped CeO₂(110) surfaces are shown in Figure 1. For CeO₂(110) (Figure 1(a)), the calculated formation energy of an O_v is 1.73 eV, which is much lower than that (2.57 eV) of CeO₂(111),²³ indicating that CeO₂(110) is easier to be reduced than CeO₂(111). This is consistent with previous studies.⁴⁹ To keep the charge balance, two Ce⁴⁺ need be reduced to Ce³⁺ after removing one surface oxygen. Since the position of Ce³⁺ can affect the energy, several configurations with Ce³⁺ at different positions were considered (Figure S1). It was found that the configuration with Ce³⁺ located at the one surface 5-coordinated Ce (Ce1 in Figure S1 (a)) and one 6-coordinated Ce (Ce3 in Figure S1 (a)) is the most stable one, which was thus used in this work. In this configuration, the Ce1-O1 and Ce2-O1 distances are more than 4.4 Å, satisfying the criteria for a potential FLP. As indicated in Figure S1 (a), the oxidation state of Ce1 (Ce2) is +3 (+4). O2 is in the middle of two Ce atoms (see Figure 2 (b)), resulting in Ce1/Ce2 surrounded by three oxygens. The electronic interaction between these oxygens and Ce1/Ce2 would potentially hinder the activation of adsorbates by the FLP.¹¹ Thus, the potential FLP is denoted as (Ce³⁺-Ce⁴⁺)/O quasi-FLP, which is expected to be less efficient than the FLP created by removing two oxygens of CeO₂(110) as that proposed in the previous DFT studies by Chang and coauthors.^{11, 19} The removal of O2 will lead to two Ce³⁺, which is denoted as the bi-Ce³⁺/O FLP. However, the formation of a single O_v in the unit cell is much easier than two such vacancies since the formation energy of the second O_v (2.31 eV) is much larger than that of the first O_v (1.73 eV). Therefore, in this work, the model of CeO₂(110) with one O_v (CeO₂(110)-O_v, Figure 1(b)) was considered.

To understand the stability of the Ni dopant at the surface, three configurations which replaced Ce located at different atomic layers of $CeO_2(110)$ were considered and the optimized geometries are given in Figure S2. In configuration 1, a surface Ce was replaced by a Ni atom, while in configurations 2 and 3, a second and a third layer Ce was substituted by a Ni atom, respectively. The calculations indicated that configuration 1 has the lowest energy, which is 1.13 and 2.38 eV lower than that of configurations 2 and 3, respectively. This implies that the Ni dopant on the CeO₂(110) surface is more stable than those in the sublayers. Thus, configuration 1 was selected as the model to simulate Ni doped CeO₂(110). The optimize geometry is shown in Figure 1 (c). The calculated binding energy of a Ni atom on this surface is 10.49 eV, which is significantly larger than the experimental cohesive energy (4.44 eV)⁶⁵ of bulk Ni. This suggests

that the Ni dopant at $CeO_2(110)$ surface is thermodynamically stable and it would be resistant against heat-induced aggregation.

As shown in Figure 1(c), when Ni substituted a surface Ce, a square planar configuration was formed by Ni binding to two surface O atoms and two subsurface ones. This leads to a large distortion of surface structure, resulting in two unstable 2-fold oxygen atoms. Removing one of the 2-fold O is thermally favorable with an exothermicity of -0.59 eV, which is consistent with previous studies.^{51, 53} The exothermicity suggests a likely spontaneous formation of an O_v. This is very similar to the situation of Ni doped $CeO_2(111)$.²³ The formation of this O_v leads to one 5coordinated surface Ce and one 7-coordinated subsurface Ce. Comparing the structure of Ni doped $CeO_2(110)$ with one O_v (Ni-CeO₂(110)-O_v) (Figure 1 (d)) with that of CeO₂(110)-O_v, it is found that the substitution of Ce2 by Ni makes only one Ce (Ce1) with the nonadjacent O1 form a potential FLP. To understand the valence state of Ce in Ni-CeO₂(110)-O_y, the spin density of Ni- $CeO_2(110)-O_v$ was calculated (Figure S3). No spin density was observed on Ce atoms, suggesting that the transition of $Ce^{4+} \rightarrow Ce^{3+}$ does not occur in Ni-CeO₂(110)-O_v. It might be due to the fact that the charge imbalance caused by Ni²⁺ substituting Ce⁴⁺ can be compensated by an O_v. Therefore, the Ce1/O1 FLP is denoted as mono-Ce⁴⁺/O FLP. For Ni and O2, the Ni-O2 distance is 3.52 Å. which also satisfies the criteria for an FLP (denoted as Ni/O FLP). On the other hand, the adjacent Ce1 and O2 can be seen as a CLP (denoted as Ce1/O2 CLP). These Lewis pairs might play a role in C₂H₂ hydrogenation. The model of Ni-CeO₂(110)-O_y was used to study the mechanism of C₂H₂ hydrogenation on Ni doped CeO₂.

The formation of a second O_v on Ni-CeO₂(110)-O_v can lead to two Ce³⁺, showing a similar degree of reduction to that of CeO₂(110)-O_v. Furthermore, the formation of a second O_v by removing O1, O2 or O3 was also studied. The optimized geometries are shown in Figure S4. The

calculated formation energy of the second O_v is 1.91, 1.49 and 2.00 eV for O1, O2 and O3, respectively, indicating O2 is easier to be removed than O1 and O3. For the second O_v formed by O2, several configurations with different Ce³⁺ locations were calculated and are shown in Figure S5. Configuration (a) is the most stable one and was used in this work (Figure 1 (e)), which is consistent with the previous results.⁵¹ The formation energy of 1.49 eV is also very close to the value of 1.30 eV calculated by Nolan⁵¹ and is lower than that (1.73 eV) of the first O_v on bare CeO₂(110), indicating again that Ni doping increases the reductivity of CeO₂(110). As indicated in Figure 1 (e), the removal of O2 makes Ce1 4-coordinated and reduced to +3, with a Ce1-O1 distance of 4.54 Å, forming an FLP denoted as mono-Ce³⁺/O FLP. Considering that the geometry with the second O_v formed by O2 is more stable than those with second O_v located at O1 and O3, it (denoted as Ni-CeO₂(110)-2O_v) was used to study the effect of Ce on the C₂H₂ hydrogenation.

3.2 H₂ dissociation on bare and Ni doped CeO₂(110)

For CeO₂(110)-O_v, the Ce sites and O in green circles form a (Ce³⁺-Ce⁴⁺)/O quasi-FLP (see Figure 1 (b)). To investigate its activity, the dissociation of H₂ on (Ce³⁺-Ce⁴⁺)/O quasi-FLP via a heterolytic path was calculated. (The calculated barrier for homolytic dissociation is 1.21 eV which is 1.09 eV higher than that of the heterolytic dissociation and thus not discussed here.) The calculated energetics is given in Table 1 and the corresponding geometries of H₂ dissociation are shown in Figure 2(a)-(c).

Before dissociation, H₂ weakly adsorbs on the O_v site with an adsorption energy of -0.27 eV and an H-H distance of 0.75 Å, consistent with the geometry calculated by Zhang et al.¹¹ who did not study the dissociation of H₂ on CeO₂(110)-O_v. In the TS, the H-H distance increases to 0.93 Å, while the O1-H2, Ce1-H1, and Ce2-H1 distances decrease to 1.41, 2.91, and 2.74 Å, respectively. The cleavage of the H-H bond needs to overcome a barrier of 0.12 eV, which is

significantly lower than that (0.55 eV¹⁹, 0.45 eV⁴⁵) on the CLP of the defect-free CeO₂(110), and is very close to that (0.07 eV)^{11, 19} on the bi-Ce³⁺/O FLP of CeO₂(110)-2O_v, implying that (Ce³⁺-Ce⁴⁺)/O quasi-FLP promotes H₂ dissociation. Moreover, the barrier is 0.40 eV lower than that (0.52 eV)²³ on CeO₂(111)-O_v, suggesting that CeO₂(110)-O_v is more active than CeO₂(111)-O_v for H₂ dissociation. After the reaction, the H₂ breaks into an O-H and a Ce-H hydride. During the dissociation process, O2 moves away from the bridge site formed by the Ce³⁺-Ce⁴⁺, suggesting that the transformation of the (Ce³⁺-Ce⁴⁺)/O quasi-FLP to a more efficient (Ce³⁺-Ce⁴⁺)/O FLP is relatively easy. This is consistent with the discussion of dynamic FLPs on CeO₂ by Huang et al.⁶⁶ To conclude, the (Ce³⁺-Ce⁴⁺)/O quasi-FLP shows high activity for H₂ dissociation.

On Ni-CeO₂(110)-O_v, there are two potential FLPs, namely the Ni/O FLP and mono-Ce⁴⁺/O FLP. On the other hand, there is also a Ce1/O2 CLP. Our calculations indicated that the adsorption of H on the square planar Ni is not stable which migrated to the neighboring 2-fold O site during optimization, implying that the Ni/O FLP is inactive. Thus, H₂ dissociation on the Ni/O FLP was not considered. To understand the activity of these sites, H₂ dissociation on mono-Ce⁴⁺/O FLP (Path I) and Ce1/O2 CLP (Path II) was studied. The reaction and activation energies of Path I are given in Table 1. The related geometries for stationary points in Path I and Path II are shown in Figure 2 (f)-(h) and Figure S6 (a)-(c), respectively. For both paths, H₂ firstly adsorbed on the O_v site with the adsorption energy of –0.21 eV and –0.23 eV, respectively. Along Path I, the TS (Figure 2(g)) is stabilized by O1 and Ce1 with the distances of 1.28, 2.54 and 0.99 Å for the O2-H1, Ce1-H2 and H1-H2 pairs, respectively. The dissociation results in the O-H and Ce-H species by surpassing a barrier of 0.41 eV with an endothermicity of 0.21 eV. For Path II, the TS is also stabilized by Ce1 and O1 and the activation barrier of 0.54 eV, which is 0.13 eV higher than that (0.41 eV) of Path I, suggests that the mono-Ce⁴⁺/O FLP is more active than Ce1/O2 CLP. At the

TS (Figure S5 (b)), the H-H distance extends to 1.02 Å with the O1-H1, Ce1-H1 and Ce1-H2 distances reduced to 1.27, 2.28 and 2.45 Å, respectively. In the final state (Figure S6 (c)), H₂ dissociates into O-H and Ce-H with an endothermicity of 0.04 eV. On Ni-CeO₂(110)-O_v, hence, our results suggest that H₂ prefers to dissociate via Path I. The barrier (0.41 eV) of this path is 0.29 eV higher than that on CeO₂(110)-O_v, but is about 0.1 eV lower than that (0.50 eV)²³ on Ni-CeO₂(111)-O_v and lower than that of the heterolytic dissociation on o-terminated step site of CeO₂(111) (0.48 to 0.73 eV),^{45,46} showing the efficiency of Ni-CeO₂(110)-O_v.

On Ni-CeO₂(110)-2O_y, the Ni/O FLP formed by Ni and O2 is absent due to the removal of O2. The possibility of H₂ dissociation on Ni/O3 was firstly studied. The optimized geometries of H₂ adsorption and dissociation product (H-Ni + H-O) are displayed in Figure S7. However, when the adsorbed H_2 and the dissociation product as the IS and FS states of the CI-NEB calculations were used to search for the transition state, it found that H₂ prefers to dissociate into H-O and H-Ce (The geometry is shown in Figure 2 (m)) rather than form H-Ni and H-O (Figure S7 (b). Therefore, only H₂ dissociation on the mono-Ce³⁺/O FLP was studied. The related geometries and the reaction/activation energies are given in Figure 2 (k)-(m) and Table 1, respectively. The H₂ dissociation on Ni-CeO₂(110)-2O_y is similar to that on Ni-CeO₂(110)-O_y. As shown in Figure 2 (k)-(m), the weakly adsorbed H₂ (-0.22 eV) dissociates into Ce-H and O-H groups via a heterolytic path. At the TS, the distance of H-H is increased to 0.98 Å, while the Ce1-H and O1-H distances are reduced to 2.58 and 1.31 Å, respectively, underscoring the role of the mono-Ce³⁺/O FLP in the stabilization of the TS. The calculated barrier of H₂ dissociation is 0.13 eV, about 0.28 eV lower than that on mono-Ce⁴⁺/O FLP and very close to that (0.12 eV) on the (Ce³⁺-Ce⁴⁺)/O quasi-FLP of $CeO_2(110)-O_v$, suggesting that the reduction of Ce from +4 to +3 states enhances the activity of the mono-Ce/O FLP for H₂ dissociation. Moreover, the barrier (0.13 eV) is much lower than that

of the heterolytic dissociation of H₂ on the step sites of CeO₂(111) (0.48 to 0.73 eV),^{45, 46} showing Ni-CeO₂(110)-2O_v is effective for H₂ dissociation.

The stability of the Ce-H hydride resulted from H₂ dissociation is quite important for the subsequent C₂H₂ hydrogenation, so that the migration of the hydride on CeO₂(110)-O_v, Ni-CeO₂(110)-O_v and Ni-CeO₂(110)-2O_v were investigated. The corresponding geometries are shown in Figure 2 (c)-(e), (h)-(j) and (m)-(o), respectively, and the reaction and activation energies are listed in Table 1. On CeO₂(110)-O_v, the H migration from Ce to neighbor O needs to overcome a barrier of 1.06 eV, confirming its stability. On Ni-CeO₂(110)-O_v, the migration barrier is 0.73 eV, implying that the Ce-H hydride is also quite stable. On Ni-CeO₂(110)-2O_v, the barrier is 1.14 eV, again indicating the high stability of Ce-H hydride. In addition, these barriers (0.73 and 1.14 eV) are much higher than those of the low-coordinated Ce hydride migration (0 to 0.55 eV)⁴⁶ on the step sites of CeO₂(111). Based on these results, we thus conclude that the hydride formed by heterolytic dissociation of H₂ is stable and the subsequent C₂H₂ hydrogenation step on bare and Ni doped CeO₂(110) proceeds with the hydride.

3.3 C₂H₂ hydrogenation on bare and Ni doped CeO₂(110)

As stated above, on $CeO_2(110)-O_v$, the $(Ce^{3+}-Ce^{4+})/O$ quasi-FLP facilitates H₂ dissociation via a heterolytic path. C₂H₂ hydrogenation should hence proceed with the resulting Ce-H hydride and O-H groups, similar to the reaction path on $CeO_2(111)$.²³ The corresponding energetics of the hydrogenation step are listed in Table 1 and geometries displayed in Figure 3 (a)-(f).

Before reaction, C_2H_2 weakly adsorbed on the surface with an adsorption energy of -0.38 eV. The adsorbed C_2H_2 species first reacts with H of the Ce-H hydride to form a weakly adsorbed C_2H_3 species (denoted as $C_2H_3^*$ (1)) (Figure 3(c)) by releasing 0.03 eV of energy. The calculated

barrier of this hydrogenation step is 0.43 eV. Then, $C_2H_3^*$ (1) moves to a more stable adsorption state (C₂H₃* (Ce) in Figure 3(d)) by binding strongly to both Ce1 and Ce2 with the C1-Ce1 and C1-Ce2 distances of 2.93 and 2.94 Å, respectively. The adsorption energy of C₂H₃* (Ce) is -1.74 eV. It can directly react with the H on O1 to form C₂H₄ (Figure 3 (f)) by overcoming a barrier of 0.32 eV. The hydrogenation process is very similar to that on the bi-Ce³⁺/O FLP of CeO₂(110)- $2O_{v}$. However, the barrier (0.32 eV) of the second hydrogenation step is about 0.26 eV lower than that (0.58 eV) on the bi-Ce³⁺/O FLP of CeO₂(110)-2O_v.¹⁹ As a result, for CeO₂(110)-O_v, the ratedetermining step is the addition of the first hydrogen, while for $CeO_2(110)-2O_{y_1}^{19}$ it is the addition of the second hydrogen. This might be due to the fact that on CeO₂(110)-2O_v, the Ce in Ce/O FLP is more exposed than that on $CeO_2(110)-O_v$. On Ni-CeO₂(110)-O_v, the hydrogenation of C_2H_2 also starts from the heterolytic products. The calculated reaction and activation energies are also shown in Table 1 and the corresponding geometries displayed in Figure 3 (g)-(l). C_2H_2 physisorption on Ni-CeO₂(110)-O_y has a binding energy of -0.49 eV. The weakly adsorbed C₂H₂ (Figure 3 (g)) is first hydrogenated by the hydride H, producing a weakly adsorbed C_2H_3 (C_2H_3 *(1), (Figure 3(i)). This step releases an energy of 0.74 eV with a barrier of 0.28 eV. Before further hydrogenation, it transforms to a more stable adsorption state of $C_2H_3^*$ (Ce) (Figure 3(j)) with the adsorption energy of -1.19 eV and with a C1-Ce1 distance of 2.55 Å. Finally, C₂H₃* (Ce) reacted with H bound to O to form C₂H₄ by overcoming a minor barrier of 0.07 eV, which is much lower than that (0.32 eV) on CeO₂(110)-O_v. This can be explained by the smaller adsorption energy of C_2H_3 (Ce) on the mono-Ce⁴⁺/O FLP (-1.19 eV) than that on the (Ce³⁺-Ce⁴⁺)/O quasi-FLP (-1.74 eV).

On Ni-CeO₂(110)-2O_v, the reaction and activation energies for the C_2H_2 hydrogenation are given in Table 1 and the geometries of the stationary points are shown in Figure 4. C_2H_2 is first

adsorbed on the surface of Ni-CeO₂(110)-2O_v with the C1-Ce1, C2-Ce1 and C2-H1 distances of 3.14, 3.18 and 3.25 Å and with the adsorption energy of -0.61 eV. The adsorbed C₂H₂ then reacts with the hydride H to form C₂H₃*(Ce) by overcoming a barrier of 0.40 eV, which is very similar to that on CeO₂(110)-O_v, but 0.12 eV higher than that on Ni-CeO₂(110)-O_v. In contrast to the cases on CeO₂(110)-O_v and Ni-CeO₂(110)-O_v, on Ni-CeO₂(110)-2O_v, the intermediate C₂H₃* (Ce) is directly formed via the reaction of C₂H₂* with the H adsorbed on Ce1. Finally, C₂H₃*(Ce) abstracts the H adsorbed on O producing C₂H₄* with a barrier of 0.32 eV, which is 0.25 eV higher than that on Ni-CeO₂(110)-O_v. The results indicates that the reduction of Ce⁴⁺ to Ce³⁺ in the mono-Ce/O FLP increases the barrier of first and second hydrogenation step.

The calculated energy profiles of C_2H_2 hydrogenation on $CeO_2(110)-O_v$, Ni-CeO_2(110)-O_v and Ni-CeO_2(110)-2O_v are shown in Figure 5. To compare the catalytic activities of CeO_2(110) and CeO_2(111), the energy profiles of bare and Ni doped CeO_2(111) surfaces with one oxygen vacancy (CeO_2(111)-O_v and Ni-CeO_2(111)-O_v) are also included in the same figure. For H₂ dissociation, on CeO_2(110)-O_v and Ni-CeO_2(110)-2O_v, the barrier (about 0.1 eV) is significantly lower than that (about 0.5 eV) on CeO_2(111)-O_v and Ni-CeO_2(111)-O_v. Even for Ni-CeO_2(110)-O_v, the barrier (0.41 eV) is about 0.1 eV lower than that on CeO_2(111)-O_v and Ni-CeO_2(111)-O_v. The results indicate a higher efficiency of CeO_2(110) for H₂ dissociation than CeO_2(111). For the first hydrogenation step, the barriers on CeO_2(110)-O_v (0.43 eV), Ni-CeO_2(110)-2O_v (0.40 eV), and CeO_2(111)-O_v (0.37 eV) are very close to each other, but higher than those on Ni-CeO_2(110)-O_v (0.28 eV) and Ni-CeO_2(111)-O_v (0.13 eV). This difference suggests that the barrier of first hydrogenation step is closely related to the oxidation state of Ce since on CeO_2(110)-O_v (0.43 eV), Ni-CeO_2(110)-2O_v and CeO_2(111)-O_v, the Ce³⁺ takes part in forming Ce/O FLPs while on Ni $CeO_2(110)-O_v$ and Ni-CeO_2(111)-O_v, Ce⁴⁺ is in the Ce/O FLPs. For the second hydrogenation step, the barriers on CeO_2(110)-O_v (0.32 eV), Ni-CeO_2(110)-O_v (0.07 eV) and Ni-CeO_2(110)-2O_v (0.32 eV) are all much lower than the those on CeO_2(111)-O_v (0.70 eV) and Ni-CeO_2(111)-O_v (0.62 eV), showing that the second hydrogenation step strongly depends on the surface structure. Judging from the rate-determining barrier, it found that on bare and doped CeO_2(110), the barrier (about 0.4 eV) is about 0.2 eV lower than that on bare (0.70 eV) and doped (0.62 eV) CeO_2(111). Thus, CeO_2(110) is more active than CeO_2(111) for acetylene hydrogenation, consistent with the experimental study.¹⁴

On CeO₂(110)-O_v/Ni-CeO₂(110)-2O_v, the barrier of first hydrogenation step (0.43/0.40 eV) is not only higher than that of the second hydrogenation step (0.32/0.32 eV), but also higher than that (0.12/0.13 eV) of H₂ dissociation. Thus, for CeO₂(110)-O_v and Ni-CeO₂(110)-2O_v, the first hydrogenation step is likely to control the reaction rate. While for Ni-CeO₂(110)-O_v, the barrier (0.41 eV) of H₂ dissociation is higher than that (0.28 eV) of the first hydrogenation step and that (0.07 eV) of second hydrogenation step, so that H₂ dissociation becomes the rate-determining step. The change of rate-determining step may be related to the different types of Ce species involved in the active sites (FLPs) since in CeO₂(110)-O_v, it is Ce⁴⁺ participating in the Ce/O FLPs.

In order to understand the effect of Ce on the activities of Ce/O FLPs, the density of states (DOSs) of CeO₂(110)-O_v, Ni-CeO₂(110)-O_v and Ni-CeO₂(110)-2O_v were calculated and shown in Figure 6. The corresponding total and partial DOSs of O and Ce forming FLPs are given in the left and right panels, respectively. The results suggest that the total and partial DOSs of O 2*p* are very similar. However, comparing the results of Ce 4*f* states, it is found that there is a peak in the range from –2 to 0 eV for Ce1/Ce1 of CeO₂(110)-O_v/Ni-CeO₂(110)-2O_v, while no peak is observed in

this range for Ce1 of Ni-CeO₂(110)-O_v. The closer to the Fermi level, the more active are Ce 4*f* valence electrons states. Thus, it can be expected that the Ce³⁺ in CeO₂(110)-O_v and Ni-CeO₂(110)-2O_v would have stronger interaction with H and C₂H₃. It is confirmed by the larger adsorption energy of H and C₂H₃ on Ce in CeO₂(110)-O_v (-1.88 eV for H, -1.84 eV for C₂H₃) and in Ni-CeO₂(110)-2O_v (-1.69 eV for H, -1.60 eV for C₂H₃) than that in Ni-CeO₂(110)-O_v (-1.22 eV for H and -1.19 eV for C₂H₃). The stronger interaction between Ce and H leads to higher activities for H₂ dissociation, resulting in lower barriers than those of the first hydrogenation step. Furthermore, the stronger adsorption of C₂H₃ presumably leads to higher barriers of the second hydrogenation step.

4. Conclusions

In this work, H₂ dissociation and C₂H₂ hydrogenation on bare and Ni doped CeO₂(110) surfaces were investigated using the density functional theory. For CeO₂(110), the endothermic formation of one O_v creates a (Ce³⁺-Ce⁴⁺)/O quasi-FLP. Ni doping leads to the exothermic formation of first O_v and the easier generation of second O_v. On Ni-CeO₂(110)-O_v and Ni-CeO₂(110)-2O_v, one Ce and a non-adjacent O form a Ce⁴⁺/O FLP and a Ce³⁺/O FLP, respectively. It is found that both the (Ce³⁺-Ce⁴⁺)/O quasi-FLP and Ce/O FLP can promote the heterolytic dissociation of H₂ and hydrogenation of acetylene by the heterolytic products of Ce-H and O-H species.

For the (Ce³⁺-Ce⁴⁺)/O quasi-FLP and Ce³⁺/O FLP, the rate-determining step is the addition of the first hydrogen with a barrier of 0.43 and 0.40 eV, respectively. With the Ce⁴⁺/O FLP of Ni-CeO₂(110)-O_v, on the other hand, the slowest step is the H₂ dissociation with a barrier of 0.41 eV. The change of rate-determining step can be attributed to the variation of the oxidation state of Ce. The Ce³⁺ species has a stronger interaction with adsorbates, leading to a higher activity for H₂ dissociation but increasing the barriers of first and second hydrogenation steps. As a result, the reduction of Ce in the Ce/O FLP enhances the activity of H₂ dissociation but suppresses the addition of first and second hydrogen, thus leading to the changes of rate-determining step. Moreover, our result reveals that the hydrogenation activity is strongly affected by the crystal facet. Both the bare and doped CeO₂(110) show a much lower rate-determining barrier than their CeO₂(111)) counterparts, confirming higher activity of CeO₂(110) than CeO₂(111) for acetylene hydrogenation, which is consistent with experimental observations. The results provide useful insights in developing effective catalysts.

Conflicts of interest:

There are no conflicts of interest to declare.

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References

1 G. C. Bond, Metal-catalysed reactions of hydrocarbons, Springer, 2005, p.

2 B. Bridier, N. Lopez and J. Perez-Ramirez, Dalton Trans. 2010, 39, 8412-8419.

3 D. Teschner, J. Borsodi, A. Wootsch, Z. Révay, M. Hävecker, A. Knop-Gericke, S. D. Jackson and R. Schlögl, *Science* 2008, *320*, 86-89.

4 M. Crespo-Quesada, F. Cárdenas-Lizana, A.-L. Dessimoz and L. Kiwi-Minsker, ACS Catal. 2012, 2, 1773-1786. 5 T. Mitsudome and K. Kaneda, Green Chem. 2013, 15, 2636-2654.

6 J. Moon, Y. Cheng, L. L. Daemen, M. Li, F. Polo-Garzon, A. J. Ramirez-Cuesta and Z. Wu, ACS Catal. 2020, 10, 5278-5287.

7 J. Kammert, J. Moon and Z. Wu, *Chin. J. Catal* 2020, *41*, 901-914.

8 X. Huang, K. Zhang, B. Peng, G. Wang, M. Muhler and F. Wang, ACS Catal. 2021, 11, 9618-9678.

9 T. Montini, M. Melchionna, M. Monai and P. Fornasiero, Chem. Rev. 2016, 116, 5987-6041.

10 Z. Zhang, Z.-Q. Wang, Z. Li, W.-B. Zheng, L. Fan, J. Zhang, Y.-M. Hu, M.-F. Luo, X.-P. Wu, X.-Q. Gong, W. Huang and J.-Q. Lu, *ACS Catal.* 2020, *10*, 14560-14566.

11 S. Zhang, Z.-Q. Huang, Y. Ma, W. Gao, J. Li, F. Cao, L. Li, C.-R. Chang and Y. Qu, *Nat. Commun.* 2017, *8*, 15266.

12 G. Vilé, B. Bridier, J. Wichert and J. Pérez-Ramírez, Angew. Chem. Int. Ed. 2012, 51, 8620-8623.

13 G. Vilé, S. Colussi, F. Krumeich, A. Trovarelli and J. Pérez-Ramírez, *Angew. Chem. Int. Ed.* 2014, 53, 12069-12072.

14 T. Cao, R. You, Z. Li, X. Zhang, D. Li, S. Chen, Z. Zhang and W. Huang, *Appl. Surf. Sci.* 2020, *501*, 144120. 15 T. Cao, R. You, X. Zhang, S. Chen, D. Li, Z. Zhang and W. Huang, *Phys. Chem. Chem. Phys.* 2018, *20*, 9659-9670.

16 K. Werner, X. Weng, F. Calaza, M. Sterrer, T. Kropp, J. Paier, J. Sauer, M. Wilde, K. Fukutani, S. Shaikhutdinov and H.-J. Freund, *J. Am. Chem. Soc.* 2017, *139*, 17608-17616.

17 C. Riley, A. De La Riva, S. Zhou, Q. Wan, E. Peterson, K. Artyushkova, M. D. Farahani, H. B. Friedrich, L. Burkemper, N.-V. Atudorei, S. Lin, H. Guo and A. Datye, *ChemCatChem* 2019, *11*, 1526-1533.

18 J. Carrasco, G. Vilé, D. Fernández-Torre, R. Pérez, J. Pérez-Ramírez and M. V. Ganduglia-Pirovano, J. Phys. Chem. C 2014, 118, 5352-5360.

19 Z.-Q. Huang, L.-P. Liu, S. Qi, S. Zhang, Y. Qu and C.-R. Chang, ACS Catal. 2018, 8, 546-554.

20 G. Vilé, P. Dähler, J. Vecchietti, M. Baltanás, S. Collins, M. Calatayud, A. Bonivardi and J. Pérez-Ramírez, J. Catal. 2015, 324, 69-78.

21 M. García-Melchor, L. Bellarosa and N. López, ACS Catal. 2014, 4, 4015-4020.

22 S. Zhou, L. Gao, F. Wei, S. Lin and H. Guo, J. Catal. 2019, 375, 410-418.

23 C. Riley, S. Zhou, D. Kunwar, A. De La Riva, E. Peterson, R. Payne, L. Gao, S. Lin, H. Guo and A. Datye, *J. Am. Chem. Soc.* 2018, *140*, 12964-12973.

24 D. W. Stephan, J. Am. Chem. Soc. 2015, 137, 10018-10032.

25 D. W. Stephan, Acc. Chem. Res. 2014, 48, 306-316.

26 H. Lee, Y. N. Choi, D.-W. Lim, M. M. Rahman, Y.-I. Kim, I. H. Cho, H. W. Kang, J.-H. Seo, C. Jeon and K. B. Yoon, *Angew. Chem. Int. Ed.* 2015, *54*, 13080-13084.

27 X. Sun, B. Li, T. Liu, J. Song and D. S. Su, Phys. Chem. Chem. Phys. 2016, 18, 11120-11124.

28 K. K. Ghuman, L. B. Hoch, T. E. Wood, C. Mims, C. V. Singh and G. A. Ozin, ACS Catal. 2016, 6, 5764-5770.

29 Z. Chen, J. Zhao, J. Zhao, Z. Chen and L. Yin, *Nanoscale* 2019, *11*, 20777-20784.

30 J. Zhao, X. Liu and Z. Chen, ACS Catal. 2017, 7, 766-771.

31 Q. Wan, J. Li, R. Jiang and S. Lin, Phys. Chem. Chem. Phys. 2021, 23, 24349-24356.

32 Z. Wu, Y. Cheng, F. Tao, L. Daemen, G. S. Foo, L. Nguyen, X. Zhang, A. Beste and A. J. Ramirez-Cuesta, J. Am. Chem. Soc. 2017, 139, 9721-9727.

33 Z. Li, K. Werner, K. Qian, R. You, A. Płucienik, A. Jia, L. Wu, L. Zhang, H. Pan, H. Kuhlenbeck, S. Shaikhutdinov, W. Huang and H.-J. Freund, *Angew. Chem. Int. Ed.* 2019, *58*, 14686-14693.

34 J. Paier, C. J. Nelin, P. S. Bagus, A. Plucienik, H. Kuhlenbeck and H.-J. Freund, *J. Electron. Spectrosc. Relat. Phenom.* 2021, 147088.

35 J. Song, Z.-F. Huang, L. Pan, J.-J. Zou, X. Zhang and L. Wang, ACS Catal. 2015, 5, 6594-6599.

36 D. Albani, M. Capdevila-Cortada, G. Vilé, S. Mitchell, O. Martin, N. López and J. Pérez-Ramírez, Angew. Chem. Int. Ed. 2017, 56, 10755-10760.

37 M. S. Frei, M. Capdevila-Cortada, R. García-Muelas, C. Mondelli, N. López, J. A. Stewart, D. Curulla Ferré and J. Pérez-Ramírez, *J. Catal.* 2018, *361*, 313-321.

38 W.-H. Feng, M.-M. Yu, L.-J. Wang, Y.-T. Miao, M. Shakouri, J. Ran, Y. Hu, Z. Li, R. Huang, Y.-L. Lu, D. Gao and J.-F. Wu, ACS Catal. 2021, 11, 4704-4711.

39 Q. Wan, Y. Chen, S. Zhou, J. Lin and S. Lin, J. Mater. Chem. A 2021, 9, 14064-14073.

40 A. Trovarelli and J. Llorca, ACS Catal. 2017, 7, 4716-4735.

41 F. Jiang, S. Wang, B. Liu, J. Liu, L. Wang, Y. Xiao, Y. Xu and X. Liu, ACS Catal. 2020, 10, 11493-11509.

42 X. Zhang, R. You, D. Li, T. Cao and W. Huang, ACS Appl. Mater. Interfaces 2017, 9, 35897-35907.

43 Z. Hu, X. Liu, D. Meng, Y. Guo, Y. Guo and G. Lu, ACS Catal. 2016, 6, 2265-2279.

44 J. Han, J. Meeprasert, P. Maitarad, S. Nammuangruk, L. Shi and D. Zhang, J. Phys. Chem. C 2016, 120, 1523-1533.

45 O. Matz and M. Calatayud, ACS Omega 2018, 3, 16063-16073.

46 Z.-Q. Wang, D.-R. Chu, H. Zhou, X.-P. Wu and X.-Q. Gong, ACS Catal. 2022, 12, 624-632.

47 M. García-Melchor and N. López, J. Phys. Chem. C 2014, 118, 10921-10926.

48 W. Zhang, M. Pu and M. Lei, *Langmuir* 2020, *36*, 5891-5901.

49 J. Paier, C. Penschke and J. Sauer, Chem. Rev. 2013, 113, 3949-3985.

50 Y. Irene and N. Michael, J. Phys.: Condens. Matter 2010, 22, 135004.

51 M. Nolan, J. Mater. Chem. 2011, 21, 9160-9168.

52 M. Nolan, J. Phys. Chem. C 2011, 115, 6671-6681.

53 W. Q. Li, S. Goverapet Srinivasan, D. R. Salahub and T. Heine, *Phys. Chem. Chem. Phys.* 2016, *18*, 11139-11149.

54 G. Kresse and J. Furthmüller, Phys. Rev. B 1996, 54, 11169-11186.

55 G. Kresse and J. Furthmüller, Comput. Mater. Sci. 1996, 6, 15-50.

56 J. P. Perdew, K. Burke and M. Ernzerhof, Phys. Rev. Lett. 1996, 77, 3865-3868.

57 S. Grimme, J. Antony, S. Ehrlich and H. Krieg, J. Chem. Phys. 2010, 132, 154104.

58 P. E. Blöchl, Phys. Rev. B 1994, 50, 17953-17979.

59 M. D. Krcha and M. J. Janik, Int. J. Quantum Chem. 2014, 114, 8-13.

60 E. W. McFarland and H. Metiu, Chem. Rev. 2013, 113, 4391-4427.

61 S. Fabris, G. Vicario, G. Balducci, S. de Gironcoli and S. Baroni, J. Phys. Chem. B 2005, 109, 22860-22867.

62 G. Henkelman, B. P. Uberuaga and H. Jónsson, J. Chem. Phys. 2000, 113, 9901-9904.

63 D. W. Stephan and G. Erker, Angew. Chem. Int. Ed. 2010, 49, 46-76.

64 Y. Ma, S. Zhang, C.-R. Chang, Z.-Q. Huang, J. C. Ho and Y. Qu, Chem. Soc. Rev. 2018, 47, 5541-5553.

65 P. Janthon, S. Luo, S. M. Kozlov, F. Viñes, J. Limtrakul, D. G. Truhlar and F. Illas, *Journal of Chemical Theory and Computation* 2014, *10*, 3832-3839.

66 Z.-Q. Huang, T. Zhang, C.-R. Chang and J. Li, ACS Catal. 2019, 9, 5523-5536.

Table 1 Reaction energies (ΔE) and activation energies (E_a) for the elementary steps involved in the H₂ dissociation and C₂H₂ hydrogenation on CeO₂(110)-O_v, Ni-CeO₂(110)-O_v and Ni-CeO₂(110)-2O_v. Here I, III, IV, VI, VII, IX denote the states indicated in Figure 5.

Reactions	CeO ₂ (110)-O _v		Ni-CeO ₂ (110)-O _v		Ni-CeO ₂ (110)-2O _v	
	ΔE	Ea	ΔE	E_a	ΔE	E_a
$\mathrm{H}_{2}\!\!+\!\!*\!\!\rightarrow\!\!\mathrm{H}_{2}\!\!*(\mathrm{I})$	-0.27	-	-0.21	-	-0.22	-
$H_2^* \rightarrow H^*(O) + H^*(Ce) (III)$	-0.24	0.12	0.23	0.41	-0.00	0.13
$\mathrm{H}^{*}(\mathrm{O}) \text{+} \mathrm{H}^{*}(\mathrm{Ce}) \rightarrow 2\mathrm{H}^{*}(\mathrm{O})$	-1.63	1.06	-2.59	0.73	-2.26	1.14
$C_2H_2(g)+2H^{*+*}\rightarrow C_2H_2^{*+2}H^{*}$ (IV)	-0.38	-	-0.49	-	-0.81	-
$C_2H_2^*+2H^*\to C_2H_3^*(Ce)+H^*(VII)$	-	-	-	-	-1.29	0.40
$C_2H_2^*+2H^*\rightarrow C_2H_3^*(1)+H^*(VI)$	-0.03	0.43	-0.90	0.28	-	-
$C_2H_3^*(1) + H^* \rightarrow C_2H_3^*(Ce) + H^*(VII)$	-1.33	-	-0.45	-	-	-
C_2H_3 *(Ce)+H*→ C_2H_4 * (IX)	-0.63	0.32	-1.09	0.07	-0.68	0.32

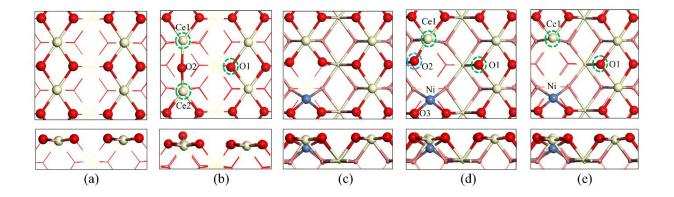


Figure 1. Top and side views of (a) $CeO_2(110)$, (b) $CeO_2(110)-O_v$, (c) Ni- $CeO_2(110)$, (d) Ni- $CeO_2(110)-O_v$ and Ni- $CeO_2(110)-O_v$. On $CeO_2(110)-O_v$, the two Ce and one O atoms in green circles form a $Ce^{3+}-Ce^{4+}/O$ quasi-FLP. On Ni- $CeO_2(110)-O_v$ and Ni- $CeO_2(110)-O_v$, the Ce and O atoms in green circles form the mono-Ce/O FLPs. On Ni- $CeO_2(110)-O_v$, the O2 in blue circle and Ce1 in green circles make a CLP. Color scheme: Ni, blue; Ce, yellow; oxygen, red; subsurface oxygen, light red.

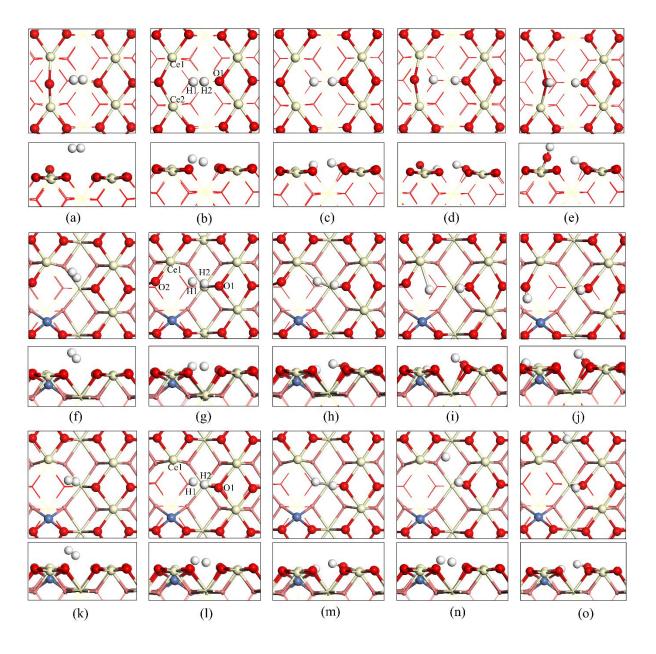


Figure 2. Top and side views of (a) H₂ adsorption (H₂*) (I), (b) TS of the H₂ dissociation (II), (c) heterolytic products (H*–Ce + H*–O) (III), (d) TS of H*–Ce migration, (e) homolytic products (H*–O + H*–O) on CeO₂(110)-O_v, (f) H₂ adsorption (H₂*) (I), (g) TS of H₂ dissociation (II), (h) heterolytic product (H*–Ce + H*–O) (III), (i) TS for H* migration from Ce to O, (j) homolytic product (H*–O + H*–O) on Ni@CeO₂(110)-O_v, (k) H₂ adsorption (H₂*) (I), (l) TS of H₂ dissociation (II), (m) heterolytic product (H*–Ce + H*–O) (III), (n) TS for H* migration from Ce to O, and (o) homolytic product (H*–O + H*–O) on Ni@CeO₂(110)-2O_v. Here, I, II and III denote the states indicated in Figure 5. Color scheme: Ni, blue; Ce, yellow; surface O, red; subsurface O, light red; H, white.

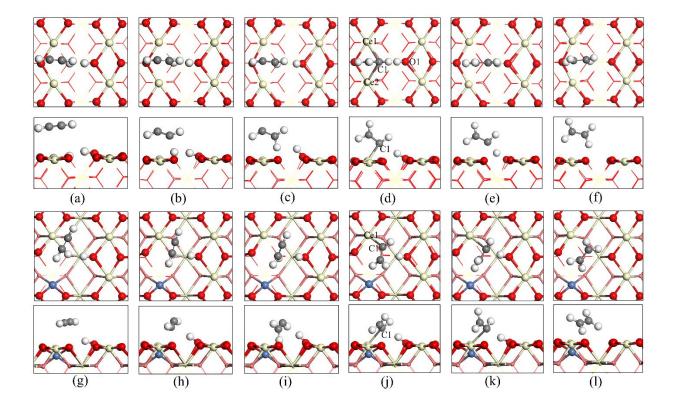


Figure 3. Top and side views of (a) $2H^* + C_2H_2^*$ (IV), (b) TS for first hydrogenation step (V), (c) $H^* + C_2H_3^*(1)$ (VI), (d) $H^* + C_2H_3^*$ (Ce) (VII), (e) TS for second hydrogenation step (VIII), and (f) $C_2H_4^*$ (IX) on $CeO_2(110)-O_v$; (g) $2H^* + C_2H_2^*(IV)$, (h) TS for first hydrogenation step (V), (i) $H^* + C_2H_3^*(1)$ (VI), (j) $H^* + C_2H_3^*(Ce)$ (VII), (k) TS for second hydrogenation step (V), (i) $H^* + C_2H_3^*(1)$ (VI), (j) $H^* + C_2H_3^*(Ce)$ (VII), (k) TS for second hydrogenation step (VIII) and (l) $C_2H_4^*$ (IX) on Ni-CeO₂(110)-O_v. Here, IV, V, VI, VII, VIII and IX denote the states indicated in Figure 5. Color scheme: Ni, blue; Ce, yellow; surface O, red; subsurface O, light red; H, white; C, grey.

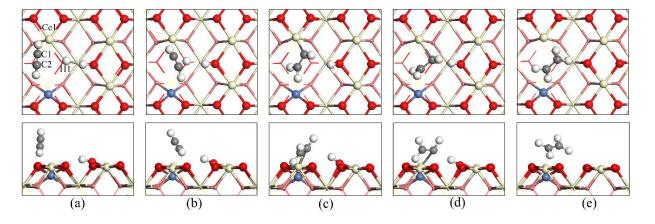


Figure 4. Top and side views of (a) $2H^* + C_2H_2^*(IV)$, (b) TS for first hydrogenation step (V), (c) $H^* + C_2H_3^*(Ce)$ (VII), (d) TS for second hydrogenation step (VIII) and (e) $C_2H_4^*$ (IX) on Ni-CeO₂(110)-2O_v. Here, IV, V, VII, VIII and IX denote the states indicated in Figure 5. Color scheme: Ni, blue; Ce, yellow; surface O, red; subsurface O, light red; H, white; C, grey.

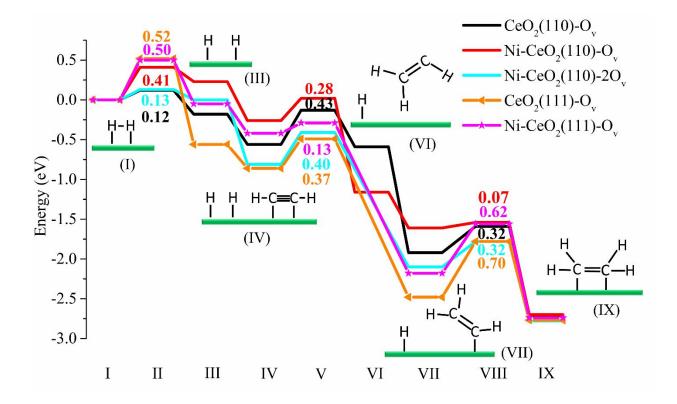


Figure 5. Calculated energy profiles of C_2H_2 hydrogenation on $CeO_2(110)-O_v$, Ni-CeO₂(110)-O_v and Ni-CeO₂(110)-2O_v. The results for $CeO_2(111)-O_v$ and Ni-CeO₂(111)-O_v are also given for comparison. The data given in the Figure indicate the activation energies (eV) of TSs. I: H_2^* , II: TS for H_2 dissociation, III: 2H* (H*-O + H*-Ce), IV: $C_2H_2^*$ + 2H*, V: TS for first hydrogenation step; VI: H*+ $C_2H_3^*(1)$, VII: H* + $C_2H_3^*$ (Ce), VIII: TS for second hydrogenation step, IX: $C_2H_4^*$. Here * denotes the adsorption state.

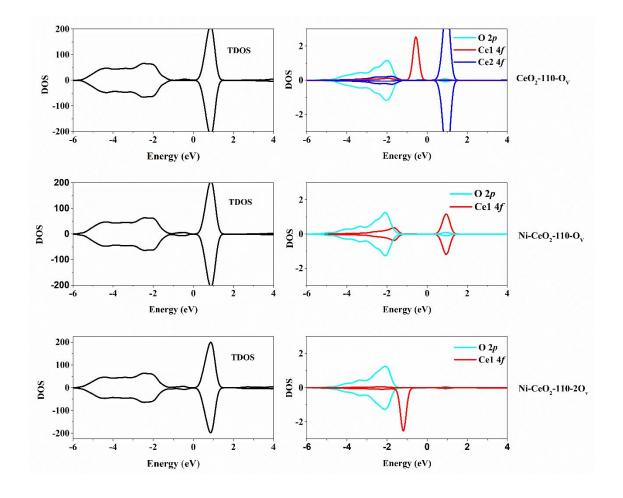


Figure 6. Total and partial densities of states of CeO₂(110)-O_v, Ni-CeO₂(110)-O_v and Ni-CeO₂(110)-2O_v.